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Revision: -

LITE-ON DCC

RELEASE

BNS-OD-FC001/A4

Property of Lite-on Only

LTV-0701

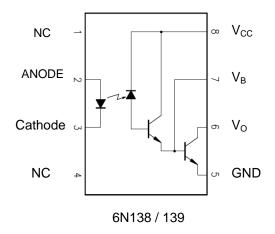
Single Channel, High Speed Optocouplers



Description

These high gain series couplers use a light emitter diode and an integrated high gain photo detector to provide extremely high current transfer ratio between input and output. Separate pins for the photodiode and output stage result in TTL compatible saturation voltage and high speed operation. Where desired the Vcc and Vo terminals may be tied together to achieve conventional photo darlington operation. A base access terminal allows a gain bandwidth adjustment to be made.





Truth Table (Positive Logic)

LED	OUT
ON	L
OFF	Н

A 0.1µF bypass Capacitor must be connected between Pin8 and Pin5



Features

- SO8 package
- High current transfer ratio 2000% typical.
- Low input current requirements 0.5mA
- High output current 60mA
- CTR guarantee 0~70°C.
- Instantaneous common mode rejection 10KV/ μ sec
- TTL compatible output 0.1V V_{OL} typical

APPLICATIONS

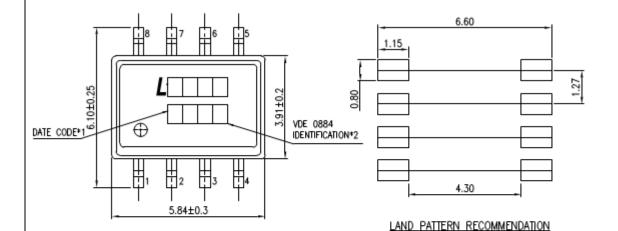
- Digital logic ground isolation
- Low input current line receiver
- Telephone ring detector
- EIA-RS-232C line receiver
- Current loop receiver
- High common mode noise line receiver

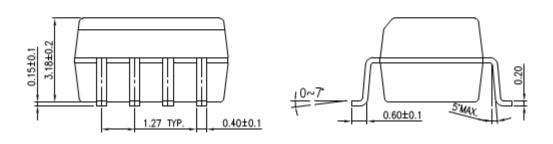
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Package Dimensions

SO8 Package (LTV-0701)





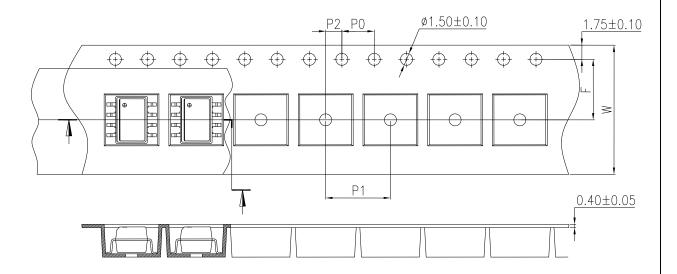
- *1. Date code
- *2. "V" to represent VDE0884

Dimensions are all in Millimeters.

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Taping Dimensions



Description	Symbol	Dimensions in millimeters (inches)
Tape wide	W	16.0±0.30(0.63)
Pitch of sprocket holes	P0	4.0±0.10(0.15)
Distance of compartment	F P2	7.5±0.10(0.295) 2±0.10(0.079)
Distance of compartment to compartment	P1	8.0±0.10(0.47)

Quantities Per Reel

Package Type	LTV-0701
Quantities (pcs)	2000

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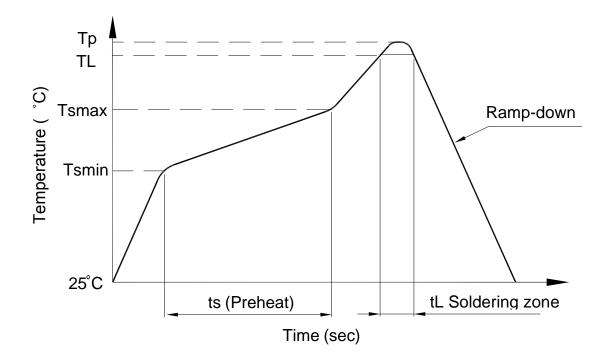
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Recommended Lead Free Reflow Profile

One time soldering reflow is recommended within the conditions below:

Profile item	Conditions
Preheat - Temperature Min (Tsmin) - Temperature Max (Tsmax) - Time (Min to Max) (Ts)	150°C 180°C 90±30°C
Soldering zone - Temperature (TL) - Time (tL)	250°C 10~15 sec
Peak temperature (TP)	260°C
Ramp-down rate	3°~ 6°C / sec



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Absolute Maximum Ratings*1

Parameter	Symbol	Device	Min	TYP	Max	Units
Storage Temperature	T _{ST}		-55		125	°C
Operating Temperature	T _A		-40		85	°C
Isolation Voltage	V _{ISO}	LTV-0701	3750			V_{RMS}
Supply Voltage	V _{CC}		-0.5		7	V
Lead Solder Temperature * 2	T _{SOL}				260	°C
Input						
Average Forward Input Current	I _F				20	mA
Reverse Input Voltage	V_R	LTV-0701			5	V
Input Power Dissipation	Pı				35	mW
Output						
Average Output Current	Io				60	mA
Supply Voltage, Output Voltage	Vcc, V _O	LTV-0701	-0.5		18	V
Output Collector Power Dissipation	P _O				100	mW

^{1.}Ambient temperature = 25°C, unless otherwise specified. Stresses exceeding the absolute maximum ratings can cause permanent damage to the device. Exposure to absolute maximum ratings for long periods of time can adversely affect reliability.

2. 260°C for 10 seconds. Refer to Lead Free Reflow Profile.

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Electrical Specifications

Parameters	Test Condition	Symbol	Device	Min	Тур	Max	Units			
Input										
Input Forward Voltage	I _F =1.6mA, T _A =25°C	V _F		1.25	1.40	1.75	V			
Input Forward Voltage Temperature Coefficient	IF=1.6mA	ΔV _F /ΔTa	LTV-0701		-1.8		mV/℃			
Input Reverse Voltage	$I_R = 10 \mu A T_A = 25 ^{\circ} C$	BV _R	L1V-0701	5	-	-	V			
Input Capacitance	V _F =0; f=1MH _Z	C _{IN}		-	60	-	pF			
Detector		•		•		•				
Correct transfer ratio	I _F =0.5mA;Vo=0.4V; Vcc=4.5V	CTD		400	2000	5000	- %			
Current transfer ratio	I _F =1.6mA;Vcc=0.4V; Vcc=4.5V	- CTR		500	1600	2600				
	I _F =0.5mA;Vcc=4.5V; I _o =2mA	V _{OL}	V _{OL}							
Logic low output voltage	I _F =1.6mA;Vcc=4.5V; I _o =8mA			V _{OL}	V			0.1	0.4	V
Logic low output voltage	I _F =5mA;Vcc=4.5V; I _o =15mA				LTV-0701			0.4		
	I _F =12mA;Vcc=4.5V; I _o =24mA				0.2					
Logic high output current	I _F =0mA, Vo=Vcc=18V T _A =25°C	Іон			0.05	100	μ Α			
Logic low supply current	I _F =1.6mA, V _o =open (Vcc=18V)	I _{ccL}		-	0.4	1.5	mA			
Logic high supply current	I _F =0mA, V _o =open; T _A =25°C (Vcc=18V)	I _{ccH}		-	0.01	10	mA			

^{*}All Typical at T_A =25°C

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SWITCHING SPECIFICATIONS (AC)

Parameter	Test Condition	Symbol	Device	Min	Тур	Max	Units	
Propagation Delay Time to	$I_{F}=0.5$ mA; $R_{L}=4.7$ K Ω			5	25	μs		
Low Output Level	$I_F=12mA; R_L=270\Omega$	t _{PHL}			0.2	1	μ3	
Propagation Delay Time to	I_F =0.5mA; R_L =4.7K Ω	- t _{PLH}			18	60	μ s	
High Output Level	$I_F=12mA; R_L=270\Omega$		LTV-0701	-	2	7	μ3	
Logic High Common Mode	I _F =0mA; V _{CM} =10V _{p-p}	Common Mode I _F =0mA; V _{CM} =10V _{p-p} ICM_I	ICM I	210 0701	1	10	_	KV/µs
Transient Immunity	$R_L=2.2K\Omega$	СМН		'	10		KV/µs	
Logic Low Common Mode	I _F =1.6mA; V _{CM} =10V _{D-D}	I _F =1.6mA; V _{CM} =10V _{p-p}	CM _L		1	10		KV/µs
Transient Immunity	$R_L=2.2K\Omega$				1	10	-	KV/μs

^{*}All Typical at T_A =25°C

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Isolation Characteristics

Parameter	Test Condition	Symbol	Min	Тур	Max	Units
Input-Output Insulation Leakage Current	45% RH, t = 5s, V _{I-O} = 3kV DC, T _A = 25°C	I _{I-O}			1.0	μΑ
Withstand Insulation Test Voltage	RH ≤ 50%, t = 1min, T _A = 25°C	V _{ISO}	3750			V_{RMS}
Input-Output Resistance	V _{I-O} = 500V DC	R _{I-O}		10 ¹²		Ω

^{*}All Typical at T_A =25°C

Notes,

- 1. AC For 1 Minute, R.H. = $40 \sim 60\%$. Isolation voltage shall be measured using the following method.
- (1) Short between anode and cathode on the primary side and between collector and emitter on the secondary side.
- (2) The isolation voltage tester with zero-cross circuit shall be used.
- (3) The waveform of applied voltage shall be a sine wave.
- 2. For 10 Seconds
- 3. Current Transfer Ratio (CTR) is defined as the ration of output collector current, Io, to the forward LED input current, IF, times 100%.
- 4. Pin 7 open.
- 5. Instantaneous common mode rejection voltage "output (1)" represents a common mode voltage variation that can hold the output above (1) level (Vo>2.0V). Instantaneous common mode rejection voltage "output (0)" represents a common mode voltage variation that can hold the output above (0) level (Vo<0.8V).
- 6. Device considered a two terminal device. Pins 1, 2, 3 and 4 shorted together and Pins 5, 6, 7 and 8 shorted together.

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Property of Lite-on Only Switching Time Test Circuit Noise Shield Pulse tr = 5ns Z_O= 50 ∨ 10% D.C. I/ f< 100ns 3 0.1 μF I_F Monitor 5 GND TPHL Figure 1: Single Channel Test Circuit for t_{PHL} and t_{PLH} Noise Shield 1 \lesssim R $_{ t L}$ 3 0.1 μF GND Pulse Gen

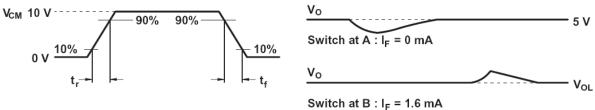


Figure 2: Single Channel Test Circuit for Common Mode Transient Immunity

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Notes:	
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